- Fast Transient Response Using Small Output Capacitor (10 μF)
- 200-mA Low-Dropout Voltage Regulator
- Available in 1.5-V, 1.8-V, 2.5-V, 3-V and 3.3-V
- Dropout Voltage Down to 170 mV at 200 mA (TPS7433)
- 3% Tolerance Over Specified Conditions
- 8-Pin SOIC Package
- Thermal Shutdown Protection

description



This device is designed to have a fast transient response and be stable with $1-\mu F$ capacitors. This combination provides high performance at a reasonable cost.

Because the PMOS device behaves as a low-value resistor, the dropout voltage is very low (typically 170 mV at an output current of 200-mA for the TPS7433). This LDO family also features a sleep mode; applying a TTL high signal to \overline{EN} (enable) shuts down the regulator, reducing the quiescent current to less than 1 μ A at T_J = 25°C.

The TPS74xx is offered in 1.5-V, 1.8-V, 2.5-V, 3-V, and 3.3-V. Output voltage tolerance is specified as a maximum of 3% over line, load, and temperature ranges. The TPS74xx family is available in 8 pin SOIC package.





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AVAILABLE OPTIONS									
ТJ	OUTPUT VOLTAGE (V)	PACKAGED DEVICES							
	ТҮР	SOIC (D)							
	3.3	TPS7433D							
	3	TPS7430D							
-40°C to 125°C	2.5	TPS7425D							
	1.8	TPS7418D							
	1.5	TPS7415D							

The D package is available taped and reeled. Add an R suffix to the device type (e.g., TPS7433DR).



[†] See application information section for capacitor selection details.

Figure 1. Typical Application Configuration

functional block diagram





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Terminal Functions

TERMIN	NAL	1/0	DECODIDITION						
NAME	NO.	1/0	DESCRIPTION						
EN	1	I	Enable input						
GND	6		Regulator ground						
IN	4, 5	I	Input voltage						
NC	2, 3		Not connected						
OUT	7	0	Regulated output voltage						
SENSE	8	I	Sense						

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Input voltage range [‡] , V _I	
Voltage range at EN	$-0.3 \text{ V to V}_{\text{I}} + 0.3 \text{ V}$
Peak output current	Internally limited
Continuous total power dissipation	See dissipation rating tables
Operating virtual junction temperature range, TJ	–40°C to 125°C
Storage temperature range, T _{stg}	−65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

‡ All voltage values are with respect to network terminal ground.

DISSIPATION RATING TABLE 1 – FREE-AIR TEMPERATURES

PACKAGE	AIR FLOW (CFM)	T _A < 25°C POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING
	0	568 mW	5.68 mW/°C	312 mW	227 mW
D	250	904 mW	9.04 mW/°C	497 mW	361 mW

recommended operating conditions

	MIN	MAX	UNIT
Input voltage, V _I §	2.5	7	V
Output current, IO (see Note 1)	0	200	mA
Operating virtual junction temperature, T _J (see Note 1)	-40	125	°C

§ To calculate the minimum input voltage for your maximum output current, use the following equation: VI(min) = VO(max) + VDO(max load). NOTE 1: Continuous current and operating junction temperature are limited by internal protection circuitry, but it is not recommended that the device operate under conditions beyond those specified in this table for extended periods of time.



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electrical characteristics over recommended operating free-air temperature range, $V_i = V_{O(tvp)} + 1 V$, $I_O = 1 mA$, $\overline{EN} = 0 V$, $C_O = 1 \mu F$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
	TD07445		TJ = 25°C		1.5			
	TPS7415	2.5 V < V _I < 7 V	T _J = -40°C to 125°C	1.455		1.545		
	TD07440	0.014 .14 .714	T _J = 25°C		1.8		1	
	TPS7418	2.8 V < V _I < 7 V	T _J = -40°C to 125°C	1.746		1.854		
Output voltage (10 μA to 200 mA load)	TPS7425	3.5 V < V ₁ < 7 V	TJ = 25°C		2.5		v	
(see Note 2)	1F37423	5.5 V < V < 7 V	$T_J = -40^{\circ}C$ to $125^{\circ}C$	2.425		2.575	v	
	TPS7430	4.0 V < V _I < 7 V	T _J = 25°C		3.0			
	11 37 430	4.0 V < V < 7 V	$T_J = -40^{\circ}C$ to $125^{\circ}C$	2.910		3.090		
	TPS7433	4.3 V < V ₁ < 7 V	TJ = 25°C		3.3			
	11 07 400	4.5 V < V < V	$T_{J} = -40^{\circ}C \text{ to } 125^{\circ}C$	3.201		3.399		
		$I_{O} = 1 \text{ mA}, \text{ EN} = 0 \text{ V}$	TJ = 25°C		80		μA	
			$T_{J} = -40^{\circ}C \text{ to } 125^{\circ}C$			115		
Quiescent current (GND current) (See No	nte 2)	I _O = 100 mA, EN = 0 V	T _J = 25°C		550		μA	
	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,		$T_J = -40^{\circ}C$ to $125^{\circ}C$			850		
		$I_{O} = 200 \text{ mA}, \text{ EN} = 0 \text{ V}$	TJ = 25°C		1300		μA	
	.0	$T_J = -40^{\circ}C$ to $125^{\circ}C$			1500			
Output voltage line regulation ($\Delta V_{\mbox{O}}/V_{\mbox{O}}$) (see Notes 2 and 3)	$V_{O} + 1 V < V_{I} \le 7 V$,	$T_J = 25^{\circ}C$		0.06		%/V		
Load regulation					5		mV	
Output noise voltage		BW = 300 Hz to 50 kHz, T _J = 25° C	C _O = 1 μF,		190		μVrms	
Output current Limit		V _O = 0 V			500	750	mA	
Thermal shutdown junction temperature					150		°C	
		2.5 V < V _I < 7 V, T _J = 25°C	$\overline{EN} = V_{I},$			1	μA	
Standby current		2.5 V < V _I < 7 V, T _J = −40°C to 125°C	EN = VI,			3	μA	
High level enable input voltage			2			V		
Low level enable input voltage						0.7	V	
	EN = 0 V	т	-1		1			
Input current (EN)	EN = VI		-1		1	μA		
Power supply ripple rejection (see Note 2)		f = 100 Hz, T _J = 25°C	C _O = 1 μF,		55		dB	
	TD07 (00	I _O = 200 mA,	TJ = 25°C		180		mV	
	TPS7430	I _O = 200 mA,	$T_{J} = -40^{\circ}C \text{ to } 125^{\circ}C$			350		
Dropout voltage (see Note 4)	TPS7433	I _O = 200 mA,	TJ = 25°C		170			
TPS		I _O = 200 mA,	$T_{J} = -40^{\circ}C \text{ to } 125^{\circ}C$			315		

NOTES: 2. Minimum IN operating voltage is 2.5 V or $V_{O(typ)}$ + 1 V, whichever is greater. Maximum IN voltage 7 V.

3. If $V_0 = 1.5$ V then $V_{imax} = 7$ V, $V_{imin} = 2.5$ V:

4. IN voltage equals V_O(Typ) – 100 mV; TPS7430 and TPS7433 dropout limited by input voltage range limitations (i.e., TPS7430 input voltage needs to drop to 2.9 V for purpose of this test).

Line Reg. (mV) =
$$(\%/V) \times \frac{V_O(V_{imax} - 2.5 V)}{100} \times 1000$$

If $V_O \ge 2.5$ V then $V_{imax} = 7$ V, $V_{imin} = V_O + 1$ V:

Line Reg. (mV) =
$$(\%/V) \times \frac{V_O(V_{imax} - (V_O + 1 V))}{100} \times 1000$$



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Table of Graphs

			FIGURE
Va	Output voltage	vs Output current	2, 3, 4
V _O Out	Output voltage	vs Junction temperature	5, 6
	Ground current	vs Junction temperature	7, 8
	Power supply ripple rejection	vs Frequency	12
	Output noise	vs Frequency	9
Z _O	Output impedance	vs Frequency	10
VDO	Dropout voltage	vs Junction temperature	11
	Line transient response		13, 15
	Load transient response		14, 16
	Output voltage	vs Time	17
	(Stability) Equivalent series resistance (ESR)	vs Output current	19











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TYPICAL CHARACTERISTICS







Figure 19

⁺ ESR refers to the total series resistance, including the ESR of the capacitor, any series resistance added externally, and PWB trace resistance to C_O.



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APPLICATION INFORMATION

The TPS74xx family includes five voltage regulators (1.5 V, 1.8 V, 2.5 V, 3 V, and 3.3 V).

minimum load requirements

The TPS74xx family is stable even at zero load; no minimum load is required for operation.

SENSE terminal connection

The SENSE terminal must be connected to the regulator output for proper functioning of the regulator. Normally, this connection should be as short as possible; however, the connection can be made near a critical circuit (remote sense) to improve performance at that point. Internally, SENSE connects to a high-impedance wide-bandwidth amplifier through a resistor-divider network and noise pickup feeds through to the regulator output. Routing the SENSE connection to minimize/avoid noise pickup is essential. Adding an RC network between SENSE and OUT to filter noise is not recommended because it can cause the regulator to oscillate.

external capacitor requirements

An input capacitor is not usually required; however, a ceramic bypass capacitor (1 µF or larger) improves load transient response and noise rejection if the TPS74xx is located more than a few inches from the power supply. A higher-capacitance electrolytic capacitor may be necessary if large (hundreds of milliamps) load transients with fast rise times are anticipated.

Like all low dropout regulators, the TPS74xx requires an output capacitor connected between OUT and GND to stabilize the internal control loop. The minimum recommended capacitance value is 1 μ F and the ESR (equivalent series resistance) must be at least 300 m Ω . Solid tantalum electrolytic and aluminum electrolytic are all suitable, provided they meet the requirements described previously.



Figure 20. Typical Application Circuit

regulator protection

The TPS74xx PMOS-pass transistor has a built-in back diode that conducts reverse currents when the input voltage drops below the output voltage (e.g., during power down). Current is conducted from the output to the input and is not internally limited. When extended reverse voltage is anticipated, external limiting may be appropriate.



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APPLICATION INFORMATION

regulator protection (continued)

The TPS74xx also features internal current limiting and thermal protection. During normal operation, the TPS74xx limits output current to approximately 500 mA. When current limiting engages, the output voltage scales back linearly until the overcurrent condition ends. While current limiting is designed to prevent gross device failure, care should be taken not to exceed the power dissipation ratings of the package. If the temperature of the device exceeds 150°C(typ), thermal-protection circuitry shuts it down. Once the device has cooled below 130°C (typ), regulator operation resumes.

power dissipation and junction temperature

Specified regulator operation is assured to a junction temperature of 125°C; the maximum junction temperature should be restricted to 125°C under normal operating conditions. This restriction limits the power dissipation the regulator can handle in any given application. To ensure the junction temperature is within acceptable limits, calculate the maximum allowable dissipation, PD(max), and the actual dissipation, PD, which must be less than or equal to PD(max).

The maximum-power-dissipation limit is determined using the following equation:

$$P_{D(max)} = \frac{T_{J}max - T_{A}}{R_{\theta JA}}$$

Where

T₁max is the maximum allowable junction temperature.

R_{0.IA} is the thermal resistance junction-to-ambient for the package, i.e., 172°C/W for the 8-terminal SOIC.

T_A is the ambient temperature.

The regulator dissipation is calculated using:

$$\mathsf{P}_{\mathsf{D}} = \left(\mathsf{V}_{\mathsf{I}} - \mathsf{V}_{\mathsf{O}}\right) \times \mathsf{I}_{\mathsf{O}}$$

Power dissipation resulting from guiescent current is negligible. Excessive power dissipation will trigger the thermal protection circuit.





PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
	. ,						(6)	.,			
TPS7415D	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	7415	Samples
TPS7418D	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	7418	Samples
TPS7418DG4	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	7418	Samples
TPS7425D	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	7425	Samples
TPS7430D	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	7430	Samples
TPS7433D	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	7433	Samples
TPS7433DR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	7433	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <= 1000ppm threshold. Antimony trioxide based flame retardants must also meet the <= 1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



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PACKAGE OPTION ADDENDUM

13-Aug-2021

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nor	ninal
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Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS7433DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1



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PACKAGE MATERIALS INFORMATION

5-Jan-2022



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS7433DR	SOIC	D	8	2500	350.0	350.0	43.0



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5-Jan-2022

TUBE



*All	dimensions	are	nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
TPS7415D	D	SOIC	8	75	505.46	6.76	3810	4
TPS7418D	D	SOIC	8	75	505.46	6.76	3810	4
TPS7418DG4	D	SOIC	8	75	505.46	6.76	3810	4
TPS7425D	D	SOIC	8	75	505.46	6.76	3810	4
TPS7430D	D	SOIC	8	75	505.46	6.76	3810	4
TPS7433D	D	SOIC	8	75	505.46	6.76	3810	4

D0008A



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.

- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



D0008A

EXAMPLE BOARD LAYOUT

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



D0008A

EXAMPLE STENCIL DESIGN

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



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